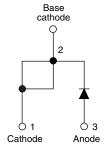


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Vishay Semiconductors

Fast Soft Recovery Rectifier Diode, 10 A





TO-220 FULL-PAK

PRODUCT SUMMARY				
Package	TO-220FP			
I _{F(AV)}	10 A			
V_{R}	1000 V, 1200 V			
V _F at I _F	1.33 V			
I _{FSM}	185 A			
t _{rr}	80 ns			
T _J max.	150 °C			
Diode variation	Single die			
Snap factor	0.6			

FEATURES

- 150 °C max. operation junction temperature
- Designed and qualified according to JEDEC-JESD47
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL E78996 approved
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 defintion (-M3 only)





COMPLIANT
HALOGEN
FREE

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-10ETF1..FP... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
V _{RRM}		1000 to 1200	V		
I _{F(AV)}	Sinusoidal waveform	10	^		
I _{FSM}		160	A A		
t _{rr}	1 A, 100 A/μs	80	ns		
V_{F}	10 A, T _J = 25 °C	1.33	V		
T _J		- 40 to 150	°C		

VOLTAGE RATINGS					
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA		
VS-10ETF10FPPbF, VS-10ETF10FP-M3	1000	1100	4		
VS-10ETF12FPPbF, VS-10ETF12FP-M3	1200	1300	4		

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I _{F(AV)}	T _C = 95 °C, 180° conduction half sine wave	10	
Maximum peak one cycle	1	10 ms sine pulse, rated V _{RRM} applied	160	Α
non-repetitive surge current	I _{FSM}	10 ms sine pulse, no voltage reapplied	185	
Maximum I ² t for fusing I ² t	124	10 ms sine pulse, rated V _{RRM} applied	128	A ² s
	1-1	10 ms sine pulse, no voltage reapplied	180	A-S
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied		A ² √s



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V_{FM}	10 A, T _J = 25 °C		1.33	V
Forward slope resistance	r _t	- T _J = 150 °C		22.9	mΩ
Threshold voltage	V _{F(TO)}			0.96	V
Maximum rayaraa laakaga aurrant	1	T _J = 25 °C	V Detect V	0.1	m A
Maximum reverse leakage current	I _{RM}	T _J = 150 °C	V _R = Rated V _{RRM}	4	mA

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Reverse recovery time	t _{rr}	I _F at 10 Apk	310	ns	I _{FM}
Reverse recovery current	I _{rr}	25 A/μs	4.7	Α	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
Reverse recovery charge	Q _{rr}	25 °C	1.05	μC	dir/ dt Q.,
Snap factor	S		0.6		dt Q _{rr}

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and sto temperature range	rage	T _J , T _{Stg}		- 40 to 150	°C	
Maximum thermal resistan junction to case	ce	R_{thJC}	DC operation	2.5		
Maximum thermal resistan junction to ambient	ce	R _{thJA}		62		
Typical thermal resistance case to heatsink	,	R _{thCS}	Mounting surface, smooth and greased 0.5			
Approximate weight				2	g	
Approximate weight				0.07	oz.	
Mounting torque	minimum			6 (5)	kgf · cm	
Mounting torque max	maximum			12 (10)	(lbf · in)	
Marking device			Case style TO-220 FULL-PAK	10ETF10FP 10ETF12FP		

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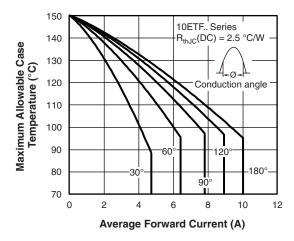


Fig. 1 - Current Rating Characteristics

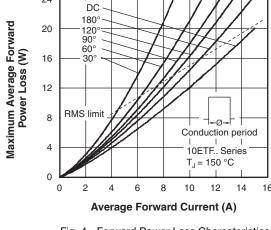


Fig. 4 - Forward Power Loss Characteristics

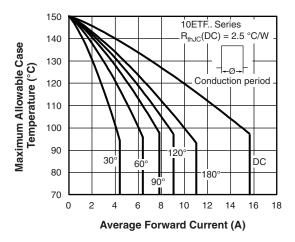


Fig. 2 - Current Rating Characteristics

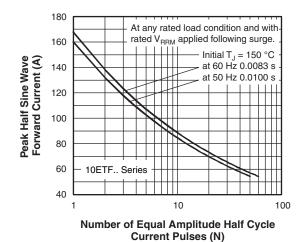


Fig. 5 - Maximum Non-Repetitive Surge Current

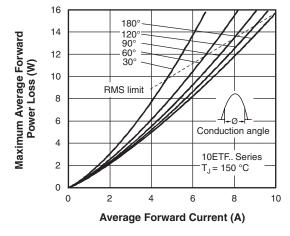


Fig. 3 - Forward Power Loss Characteristics

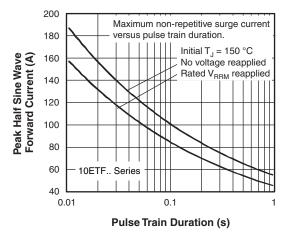


Fig. 6 - Maximum Non-Repetitive Surge Current

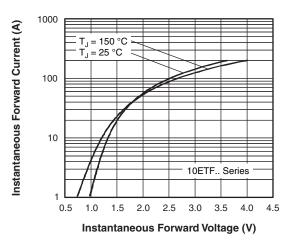


Fig. 7 - Forward Voltage Drop Characteristics

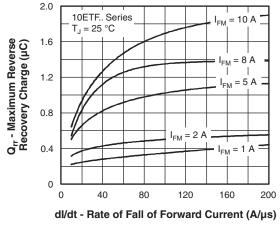


Fig. 10 - Recovery Charge Characteristics, T_{.I} = 25 °C

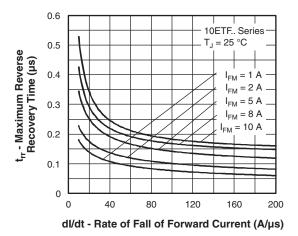


Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

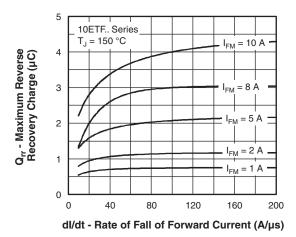


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

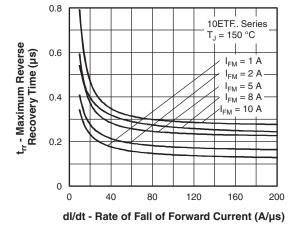


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

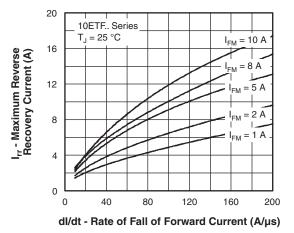


Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

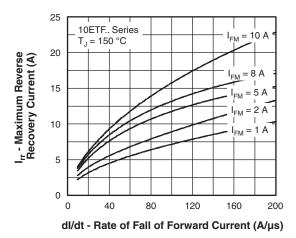


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

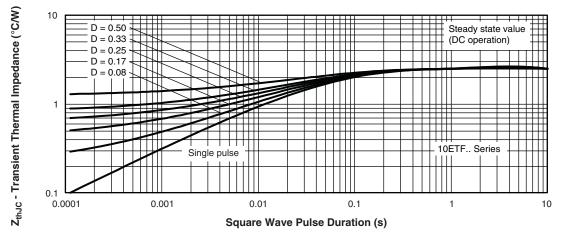
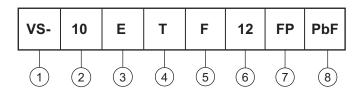


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

Current rating (10 = 10 A)

Circuit configuration:

E = Single diode

Package:

T = TO-220

5 Type of silicon:

F = Fast soft recovery rectifier

02 = 200 V Voltage code x $100 = V_{RRM}$ 04 = 400 V 06 = 600 V

FULL-PAK

Environmental digit:

• PbF = Lead (Pb)-free and RoHS compliant

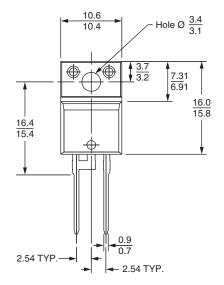
• -M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

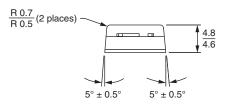
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-10ETF10FPPbF	50	1000	Antistatic plastic tubes			
VS-10ETF10FP-M3	50	1000	Antistatic plastic tubes			
VS-10ETF12FPPbF	50	1000	Antistatic plastic tubes			
VS-10ETF12FP-M3	50	1000	Antistatic plastic tubes			

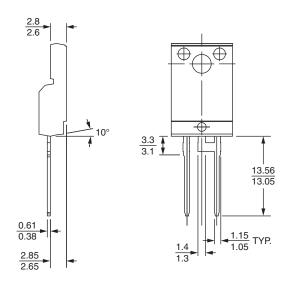
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95005</u>				
Dort marking information	TO-220 FP PbF	www.vishay.com/doc?95009		
Part marking information	TO-220 FP -M3	www.vishay.com/doc?95440		

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DIMENSIONS in millimeters







Lead assignments

Diodes

1 + 2 - Cathode

3 - Anode

Conforms to JEDEC outline TO-220 FULL-PAK



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